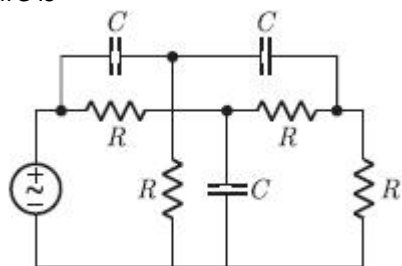


SECTION- B

(Only for candidates appearing in QURAT July'19 –DEPARTMENT E.C.E)

51. The minimum number of equations required to analyse the circuit shown in the figure is



- a. 3
- b. 4
- c. 6
- d. 7

52. A superheterodyne receiver is to operate in the frequency range 550 kHz – 1650 kHz, with the intermediate frequency of 450 kHz. Let $R = C_{max}/C_{min}$ denote the required capacitance ratio of the local oscillator and I denote the image frequency (in kHz) of the incoming signal. If the receiver is tuned to 700 kHz, then

- a. $R = 4.41, I = 1600$
- b. $R = 2.10, I = 1150$
- c. $R = 3.0, I = 600$
- d. $R = 9.0, I = 1150$

53. A sinusoidal signal with peak-to-peak amplitude of 1.536 V is quantized into 128 levels using a mid-rise uniform quantizer. The quantization-noise power is

- a. 0.768 V
- b. $48 \cdot 10^{-6} V^2$
- c. $12 \cdot 10^{-6} V^2$
- d. 3.072 V

54. The Laplace transform of $i(t)$ is given by

$$I(s) = 2/s(1+s)$$

At $t \rightarrow \infty$, The value of $i(t)$ tends to

- a. 0
- b. 1
- c. 2
- d. Infinity

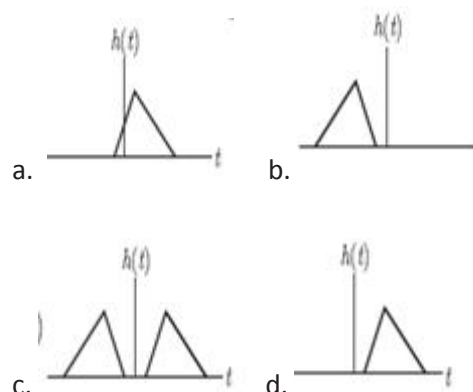
55. The first and the last critical frequency of an RC-driving point impedance function must respectively be

- a. A zero and a pole
- b. A zero and a zero
- c. A pole and a pole
- d. A pole and a zero

56. The cascade amplifier is a multistage configuration of

- a. CC – CB
- b. CE – CB
- c. CB – CC
- d. CE – CC

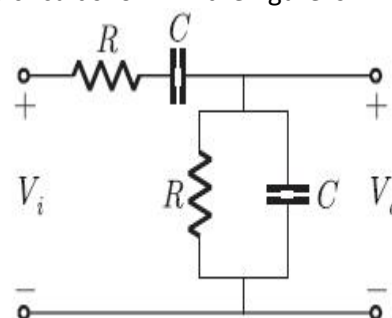
57. Which of the following can be impulse response of a causal system?



58. Despite the presence of negative feedback, control systems still have problems of instability because the

- a. Components used have non-linearities
- b. Dynamic equations of the subsystem are not known exactly.
- c. Mathematical analysis involves approximations.
- d. System has large negative phase angle at high frequencies.

59. The RC circuit shown in the figure is



- a. A low-pass filter
- b. A high-pass filter
- c. A band-pass filter
- d. A band-reject filter

60. In a pn junction diode under reverse biased the magnitude of electric field is maximum at

- a. The edge of the depletion region on the p -side
- b. The edge of the depletion region on the n -side
- c. The pn junction
- d. The centre of the depletion region on the n -side

61. The Boolean function $Y = AB + CD$ is to be realized using only 2 – input NAND gates. The minimum number of gates required is

- a. 2
- b. 3
- c. 4
- d. 5

62. In a transconductance amplifier, it is desirable to have

- a. A large input resistance and a large output resistance
- b. A large input resistance and a small output resistance
- c. A small input resistance and a large output resistance
- d. A small input resistance and a small output resistance

63. Match the following and choose the correct combination:

Group 1

- E. Newton-Raphson method
- F. Runge-kutta method
- G. Simpson's Rule
- H. Gauss elimination

Group 2

1. Solving nonlinear equations
2. Solving linear simultaneous equations
3. Solving ordinary differential equations
4. Numerical integration
5. Interpolation

- a. E - 6, F - 1, G - 5, H - 3
- b. E - 1, F - 6, G - 4, H - 3
- c. E - 1, F - 3, G - 4, H - 2
- d. E - 5, F - 3, G - 4, H - 1

64. In an ideal differential amplifier shown in the figure, a large value of (RE) .

- a. Increase both the differential and common - mode gains.

- b. Increases the common mode gain only.
- c. Decreases the differential mode gain only.
- d. Decreases the common mode gain only.

65. In delta modulation, the slope overload distortion can be reduced by

- a. Decreasing the step size
- b. Decreasing the granular noise
- c. Decreasing the sampling rate
- d. Increasing the step size

66. Calculation of Eigenvalues

Given an orthogonal matrix

$$A = \begin{bmatrix} 1 & 1 & 1 & 1 \\ 1 & 1 & -1 & -1 \\ 1 & -1 & 0 & 0 \\ 0 & 0 & 1 & 1 \end{bmatrix}$$

$[AA^T]^{-1}$ is

a. $\begin{bmatrix} \frac{1}{4} & 0 & 0 & 0 \\ 0 & \frac{1}{4} & 0 & 0 \\ 0 & 0 & \frac{1}{2} & 0 \\ 0 & 0 & 0 & \frac{1}{2} \end{bmatrix}$

b. $\begin{bmatrix} \frac{1}{2} & 0 & 0 & 0 \\ 0 & \frac{1}{2} & 0 & 0 \\ 0 & 0 & \frac{1}{2} & 0 \\ 0 & 0 & 0 & \frac{1}{2} \end{bmatrix}$

c. $\begin{bmatrix} 1 & 0 & 0 & 0 \\ 0 & 1 & 0 & 0 \\ 0 & 0 & 1 & 0 \\ 0 & 0 & 0 & 1 \end{bmatrix}$

d. $\begin{bmatrix} \frac{1}{4} & 0 & 0 & 0 \\ 0 & \frac{1}{4} & 0 & 0 \\ 0 & 0 & \frac{1}{4} & 0 \\ 0 & 0 & 0 & \frac{1}{4} \end{bmatrix}$

67. In a Direct Sequence CDMA system the chip rate is $1.2288 * 10^6$ chips per second. If the processing gain is desired to be AT LEAST 100, the data rate

- a. Must be less than or equal to $12.288 * 10^3$ bits per sec
- b. Must be greater than $12.288 * 10^3$ bits per sec
- c. Must be exactly equal to $12.288 * 10^3$ bits per sec
- d. Can take any value less than $122.88 * 10^3$ bits per sec

68. The ratio of the average energy of Constellation 1 to the average energy of Constellation 2 is

- a. $4a^2$
- b. 4
- c. 2
- d. 8

69. If

$$V_i = V \sin(\omega t) \text{ and } V = V \sin(\omega t + \phi)$$

, then the minimum and maximum values of φ (in radians) are respectively

a. $-\frac{\pi}{2}$ and $\frac{\pi}{2}$

b. 0 and $\frac{\pi}{2}$

c. $-\pi$ and 0

d. $-\frac{\pi}{2}$

70. After execution of line 7 of the program, the status of the CY and Z flags will be

- a. CY = 0, Z = 0
- b. CY = 0, Z = 1
- c. CY = 1, Z = 0
- d. CY = 1, Z = 1

71. n-type silicon is obtained by doping silicon with

- a. Germanium
- b. Aluminium
- c. Boron
- d. Phosphorus

72. Choose proper substitutes for X and Y to make the following statement correct

Tunnel diode and Avalanche photo diode are operated in X bias and Y bias respectively

- a. X: reverse, Y: reverse
- b. X: reverse, Y: forward
- c. X: forward, Y: reverse
- d. X: forward, Y: forward

73. At 300 K, for a diode current of 1 mA, a certain germanium diode requires a forward bias of 0.1435 V, whereas a certain silicon diode requires a forward bias of 0.718 V. Under the conditions state above, the closest approximation of the ratio of reverse saturation current in germanium diode to that in silicon diode is

- a. 1
- b. 5
- c. 4×10^3
- d. 8×10^3

74. When the gate-to-source voltage (V_G s) of a MOSFET with threshold voltage of 400 mV, working in saturation is 900 mV, the drain current is observed to be 1 mA. Neglecting the

channel width modulation effect and assuming that the MOSFET is operating at saturation, the drain current for an applied V_G s of 1400 mV is

- a. 0.5 mA
- b. 2.0 mA
- c. 3.5 mA
- d. 4.0 mA

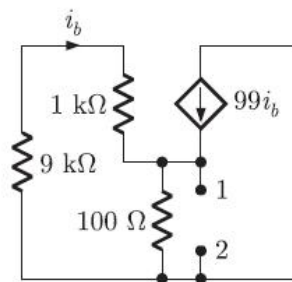
75. The action of JFET in its equivalent circuit can best be represented as a

- a. Current controlled current source
- b. Current controlled voltage source
- c. Voltage controlled voltage source
- d. Voltage controlled current source

76. The output Y of a 2-bit comparator is logic 1 whenever the 2-bit input A is greater than the 2-bit input B. The number of combinations for which the output is logic 1, is

- a. 4
- b. 6
- c. 8
- d. 10

77. The impedance looking into nodes 1 and 2 in the given circuit is ($\Omega = w$)



- a. 50 W
- b. 100 W
- c. 5 kW
- d. 10.1 kW

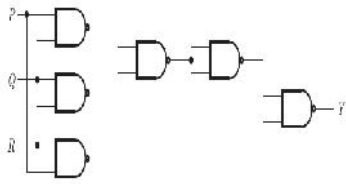
78. An analog signal is band-limited to 4 kHz, sampled at the Nyquist rate and the samples are quantized into 4 levels. The quantized levels are assumed to be independent and equally probable. If we transmit two quantized samples per second, the information rate is _____ bits / second.

- a. 1
- b. 2
- c. 3
- d. 4

79. A system is defined by its impulse response $h(n) = 2^n u(n - 2)$. The system is

- a. stable and causal
- b. causal but not stable
- c. stable but not causal
- d. unstable and non-causal

80. The output Y in the circuit below is always '1' when

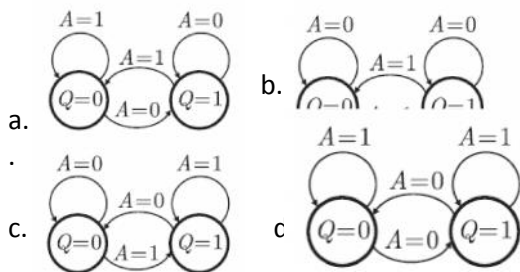
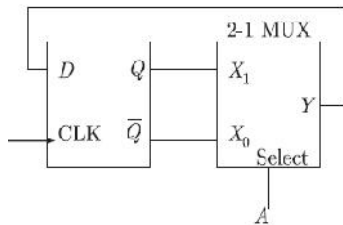


- a. Two or more of the inputs P, Q, R are '0'
- b. Two or more of the inputs P, Q, R are '1'
- c. Any odd number of the inputs P, Q, R is '0'
- d. Any odd number of the inputs P, Q, R is '1'

81. Drift current in the semiconductors depends upon

- a. Only the electric field
- b. Only the carrier concentration gradient
- c. Both the electric field and the carrier concentration
- d. Both the electric field and the carrier concentration gradient

82. The state transition diagram for the logic circuit shown is



83. The maximum value of $f(x) = x^3 - 9x^2 + 24x + 5$ in the interval $[1,6]$ is

- a. 21
- b. 25
- c. 41
- d. 46

84. With 10 V dc connected at port A, the current drawn by 7 W connected at port

B is ($\Omega = W$)

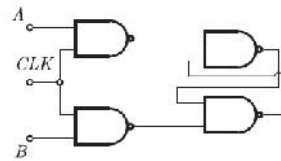
- a. 3/7 A
- b. 5/7 A
- c. 1A
- d. 9/7 A

85. For the same network, with 6 V dc connected at port A, 1 W connected at port B draws 7/3 A. If 8 V dc is connected to port A, the open circuit voltage at port B is

- a. 6 V
- b. 7 V

- c. 8 V
- d. 9 V

86. Consider the given circuit



In this circuit, the race around

- a. Does not occur
- b. Occur when $CLK = 0$
- c. Occur when $CLK = 1$ and $A = B = 1$
- d. Occur when $CLK = 1$ and $A = B = 0$

87. Two independent random variables X and Y are uniformly distributed in the interval $[-1,1]$. The probability that $\max[X,Y]$ is less than 1/2 is

- a. 3/4
- b. 9/16
- c. 1/4
- d. 2/3

88. A Zener diode, when used in voltage stabilization circuits, is biased in

- a. Reverse bias region below the breakdown voltage
- b. Reverse breakdown region
- c. Forward bias region
- d. Forward bias constant current mode

89. The solution of the differential equation $dx/dy = ky$, $y(0) = c$ is

- a. $x = ce^{-ky}$
- b. $x = ke^{cy}$
- c. $y = ce^{kx}$
- d. $y = ce^{-kx}$

90. The **Column-I** lists the attributes and the **Column-II** lists the modulation systems. Match the attribute to the modulation system that best meets it

Column-I

- P. Power efficient transmission of signals
- Q. Most bandwidth efficient transmission of voice signals
- R. Simplest receiver structure
- S. Bandwidth efficient transmission of signals with Significant dc component

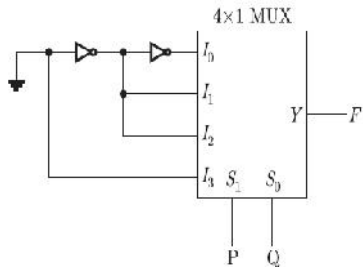
Column-II

- 1. Conventional AM
- 2. FM
- 3. VSB
- 4. SSB-SC
- a. P-4;Q-2;R-1;S-3
- b. P-2;Q-4;R-1;S-3
- c. P-3;Q-2;R-1;S-4
- d. P-2;Q-4;R-3;S-1

91. The trigonometric Fourier series of an even function does not have the

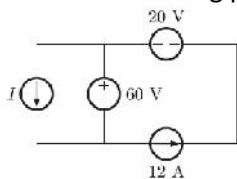
- a. DC term
- b. Cosine terms
- c. Sine terms
- d. Odd harmonic terms

92. The logic function implemented by the circuit below is (ground implies logic 0)



- a. $F = \text{AND}(P, Q)$
- b. $F = \text{OR}(P, Q)$
- c. $F = \text{XNOR}(P, Q)$
- d. $F = \text{XOR}(P, Q)$

93. In the interconnection of ideal sources shown in the figure, it is known that the 60 V source is absorbing power.



Which of the following can be the value of the current source I ?

- a. 10 A
- b. 13 A
- c. 15 A
- d. 18 A

94. In a microprocessor, the service routine for a certain interrupt starts from a fixed location of memory which cannot be externally set, but the interrupt can be delayed or rejected such an interrupt is

- a. Non-maskable and non-vectored
- b. Maskable and non-vectored
- c. Non-maskable and vectored
- d. Maskable and vectored

95. Match each differential equation in Group I to its family of solution curves from Group II

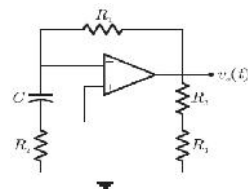
- | | |
|-------------------|-------------------|
| Group I | Group II |
| A. $dx/dy = y/x$ | 1. Circles |
| B. $dx/dy = -y/x$ | 2. Straight lines |

C. $dx/dy = x/y$ 3. Hyperbolas

D. $dx/dy = -x/y$

- a. A - 2, B - 3, C - 3, D - 1
- b. A - 1, B - 3, C - 2, D - 1
- c. A - 2, B - 1, C - 3, D - 3
- d. A - 3, B - 2, C - 1, D - 2

96. In the following a stable multivibrator circuit, which properties of $v_0(t)$ depend on R_2 ?

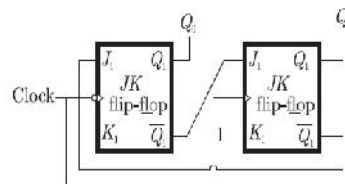


- a. Only the frequency
- b. Only the amplitude
- c. Both the amplitude and the frequency
- d. Neither the amplitude nor the frequency

97. What are the minimum number of 2- to -1 multiplexers required to generate a 2- input AND gate and a 2- input Ex-OR gate

- a. 1 and 2
- b. 1 and 3
- c. 1 and 1
- d. 2 and 2

98. What are the counting states (Q_1, Q_2) for the counter shown in the figure below



- a. 11,10,00,11,10,...
- b. 01,10,11,00,01,...
- c. 00,11,01,10,00,...
- d. 01,10,00,01,10,...

99. Norton's theorem states that a complex network connected to a load can be replaced with equivalent impedance

- a. In series with a current source
- b. In parallel with a voltage source
- c. In series with a voltage source
- d. In parallel with a current source

100. In CMOS technology, shallow P-well or N-well regions can be formed using

- a. Low pressure chemical vapour deposition
- b. Low energy sputtering
- c. Low temperature dry oxidation
- d. Low energy ion-implantation